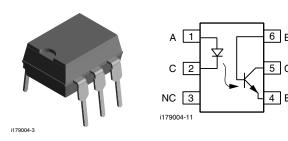




# Vishay Semiconductors

# Optocoupler, Phototransistor Output, with Base Connection



#### **DESCRIPTION**

The SFH601 is an optocoupler with a gallium arsenide LED emitter which is optically coupled with a silicon planar phototransistor detector. The component is packaged in a plastic plug-in case 20 AB DIN 41866.

The coupler transmits signals between two electrically isolated circuits.

#### **FEATURES**

- Isolation test voltage (1.0 s), 5300 V<sub>RMS</sub>
- $V_{CEsat}$  0.25 ( $\leq$  0.4) V,  $I_{F}$  = 10 mA,  $I_{C}$  = 2.5 mA
- Built to conform to VDE requirements
- · Highest quality premium device
- Long term stability
- Storage temperature, 55 ° to + 150 °C
- Material categorization: For definitions of compliance please see <a href="https://www.vishav.com/doc?99912">www.vishav.com/doc?99912</a>

# Pb-free





#### **AGENCY APPROVALS**

- UL1577, file no. E52744 system code H or J, double protection
- DIN EN 60747-5-5 (VDE 0884-5) available with option 1
- CSA 93751
- BSI IEC 60950; IEC 60065

ORDERING INFORMATION									
S F H 6	0 1 -	# X 0	# #	DIP Option 6					
PART NUMBE	ER	CTR BIN PACKAGE OPTION							
AGENCY CERTIFIED/PACKAGE		CTF	R (%)						
UL, BSI, CSA	40 to 80	63 to 125	100 to 200	160 to 320					
DIP-6	SFH601-1	SFH601-2	SFH601-3	SFH601-4					
DIP-6, 400 mil, option 6	SFH601-1X006	SFH601-2X006	SFH601-3X006	SFH601-4X006					
SMD-6, option 7	SFH601-1X007	SFH601-2X007T	SFH601-3X007(T)	SFH601-4X007(T)					
SMD-6, option 9	SFH601-1X009T	SFH601-2X009	SFH601-3X009	SFH601-4X009(T)					
VDE, cUL, UL, BSI	40 to 80	63 to 125	100 to 200	160 to 320					
DIP-6, option 1	SFH601-1X001	SFH601-2X001	-	SFH601-4X001					
DIP-6, 400 mil, option 6	SFH601-1X016	-	SFH601-3X016	SFH601-4X016					
SMD-6, option 7	SFH601-1X017	SFH601-2X017(T)	SFH601-3X017(T)	-					
SMD-6, option 9	=	-	SFH601-3X019(T)	-					

#### Note

• For additional information on the available options refer to option information.

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)									
PARAMETER	TEST CONDITION SYMBOL VALUE UNIT								
INPUT									
Reverse voltage		$V_R$	6	V					
DC forward current		I <sub>F</sub>	60	mA					
Surge forward current	t = 10 μs	I <sub>FSM</sub>	2.5	Α					
Total power dissipation		P <sub>diss</sub>	100	mW					



# **SFH601**

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<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT				
OUTPUT								
Collector emitter voltage		$V_{CEO}$	100	V				
Emitter base voltage		$V_{EBO}$	7	V				
Collector current		I <sub>C</sub>	50	mA				
Collector current	t = 1.0 ms	Ic	-	mA				
Power dissipation		P <sub>diss</sub>	150	mW				
COUPLER								
Isolation test voltage between emitter and detector	t = 1.0 s	V <sub>ISO</sub>	5300	V <sub>RMS</sub>				
Isolation resistance	$V_{IO} = 500 \text{ V}, T_{amb} = 25 \text{ °C}$ $R_{IO}$		≥ 10 <sup>12</sup>	Ω				
Isolation resistance	V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 100 °C	R <sub>IO</sub>	≥ 10 <sup>11</sup>	Ω				
Storage temperature range		T <sub>stg</sub>	- 55 to + 150	°C				
Ambient temperature range		T <sub>amb</sub>	- 55 to +100	°C				
Junction temperature		T <sub>j</sub>	100	°C				
Soldering temperature (1)	max. 10 s, dip soldering: distance to seating plane ≥ 1.5 mm	T <sub>sld</sub>	260	°C				

#### Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
  implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
  maximum ratings for extended periods of the time can adversely affect reliability.
- (1) Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)									
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT		
INPUT									
Forward voltage	I <sub>F</sub> = 60 mA		$V_{F}$		1.25	1.65	V		
Breakdown voltage	$I_R = 10 \mu A$		$V_{BR}$	6			V		
Reverse current	V <sub>R</sub> = 6 V		I <sub>R</sub>		0.01	10	μΑ		
Capacitance	V <sub>F</sub> = 0 V, f = 1 MHz		Co		25		pF		
Thermal resistance			R <sub>thja</sub>		750		K/W		
OUTPUT									
Collector emitter capacitance	$f = 1 \text{ mHz}, V_{CE} = 5 \text{ V}$		C <sub>CE</sub>		6.8		pF		
Collector base capacitance	$f = 1 \text{ mHz}, V_{CB} = 5 \text{ V}$		C <sub>CB</sub>		8.5		pF		
Emitter base capacitance	$f = 1 \text{ mHz}, V_{EB} = 5 \text{ V}$		C <sub>EB</sub>		11		pF		
Thermal resistance			R <sub>thja</sub>		500		K/W		
		SFH601-1	I <sub>CEO</sub>		2	50	nA		
Collector emitter leakage current	V <sub>CF</sub> =10 V	SFH601-2	I <sub>CEO</sub>		2	50	nA		
Collector entitler leakage current	v <sub>CE</sub> = 10 v	SFH601-3	I <sub>CEO</sub>		5	100	nA		
		SFH601-4	I <sub>CEO</sub>		5	1.65 10 50 50	nA		
COUPLER									
Saturation voltage collector emitter	$I_F = 10 \text{ mA}, I_C = 2.5 \text{ mA}$		V <sub>CEsat</sub>		0.25	0.4	V		
Capacitance (input to output)	$V_{I-O} = 0$ , $f = 1$ MHz		C <sub>IO</sub>		0.6		pF		

#### Note

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering
evaluation. Typical values are for information only and are not part of the testing requirements.



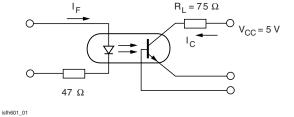
# Vishay Semiconductors

CURRENT TRANSFER RATIO									
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT		
		SFH601-1	CTR	40		80	%		
	10	SFH601-2	CTR	63		125	%		
1. // -t.V	$I_F = 10 \text{ mA}$	SFH601-3	CTR	100		125 % 200 % 320 %	%		
		SFH601-4	CTR	160		320	%		
$I_{\rm C}/I_{\rm F}$ at $V_{\rm CE} = 5.0 \text{ V}$		SFH601-1	CTR	13	30		%		
	I <sub>E</sub> = 1 mA	SFH601-2	CTR	22	45		%		
	IF = I IIIA	SFH601-3	CTR	34	70		%		
	S	SFH601-4	CTR	56	90		%		

#### Note

• Current transfer ratio and collector emitter leakage current by dash number.

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
NON-SATURATED			l l				
Current	$V_{CC} = 5 \text{ V}, R_{L} = 75 \Omega$		IF		10		mA
Rise time	$V_{CC} = 5 \text{ V}, R_{L} = 75 \Omega$		t <sub>r</sub>		2		μs
Fall time	$V_{CC} = 5 \text{ V}, R_{L} = 75 \Omega$		t <sub>f</sub>		2		μs
Turn-on time	$V_{CC} = 5 \text{ V}, R_{L} = 75 \Omega$		t <sub>on</sub>		3		μs
Turn-off time	$V_{CC} = 5 \text{ V}, R_{L} = 75 \Omega$		t <sub>off</sub>		2.3		μs
SATURATED							
		SFH601-1	I <sub>F</sub>		20		mA
O		SFH601-2	I <sub>F</sub>		10		mA
Current		SFH601-3	I <sub>F</sub>		10		mA
		SFH601-4	I <sub>F</sub>		2 2 3 2.3 20 10 10 0.5 2 3 3 4.6 11 14 14 15 3 4.2 4.2 6	mA	
		SFH601-1	t <sub>r</sub>		2		μs
Dia a tima		SFH601-2	t <sub>r</sub>		3		μs
Rise time		SFH601-3	t <sub>r</sub>		3		μs
		SFH601-4	t <sub>r</sub>		4.6		μs
		SFH601-1	t <sub>f</sub>		11		μs
Fall time		SFH601-2	2 t <sub>f</sub>		14		μs
raii ume		SFH601-3	t <sub>f</sub>		14		μs
		SFH601-4	t <sub>f</sub>		15		μs
		SFH601-1	t <sub>on</sub>		3		μs
Turn-on time		SFH601-2	t <sub>on</sub>		4.2		μs
rum-on ume		SFH601-3	t <sub>on</sub>		4.2		μs
		SFH601-4	t <sub>on</sub>		6		μs
		SFH601-1	t <sub>off</sub>		18		μs
Turn-off time		SFH601-2	t <sub>off</sub>		23		μs
rum-on ume		SFH601-3	t <sub>off</sub>		23		μs
		SFH601-4	t <sub>off</sub>		25		μs





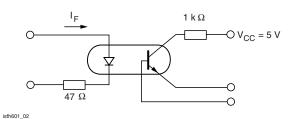


Fig. 2 - Switching Operation (with Saturation)



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SAFETY AND INSULATION RATINGS								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Climatic classification	according to IEC 68 part 1			55/100/21				
Comparative tracking index		CTI	175		399			
V <sub>IOTM</sub>			8000			V		
V <sub>IORM</sub>			890			V		
P <sub>SO</sub>					700	mW		
I <sub>SI</sub>					400	mA		
T <sub>SI</sub>					175	°C		
Creepage distance	standard DIP-6		7			mm		
Clearance distance	standard DIP-6		7			mm		
Creepage distance	400 mil DIP-6		8			mm		
Clearance distance	400 mil DIP-6		8			mm		
Insulation thickness, reinforced rated	per IEC 60950 2.10.5.1		0.4			mm		

#### Note

#### TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

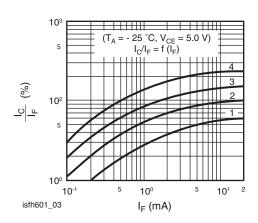
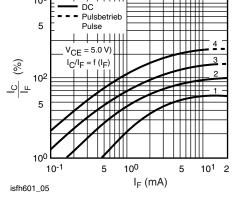


Fig. 3 - Current Transfer Ratio vs. Diode Current



10<sup>3</sup>

Fig. 5 - Current Transfer Ratio vs. Diode Current

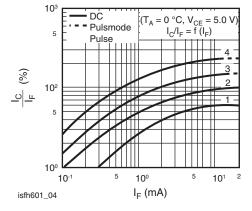


Fig. 4 - Current Transfer Ratio vs. Diode Current

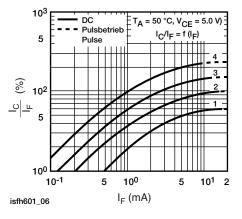


Fig. 6 - Current Transfer Ratio vs. Diode Current

As per IEC 60747-5-2, § 7.4.3.8.1, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with
the safety ratings shall be ensured by means of protective circuits.



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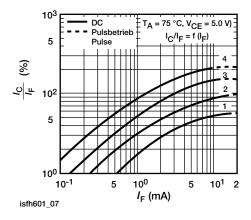


Fig. 7 - Current Transfer Ratio vs. Diode Current

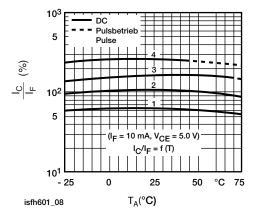


Fig. 8 - Current Transfer Ratio vs. Diode Current

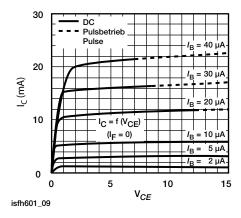


Fig. 9 - Transistor Characteristics

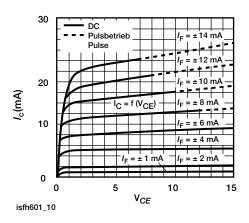


Fig. 10 - Output Characteristics

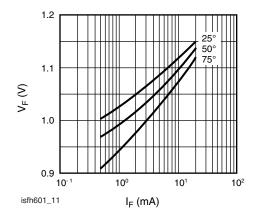


Fig. 11 - Forward Voltage

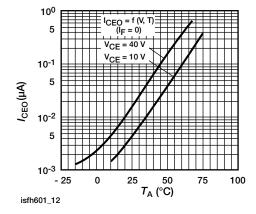


Fig. 12 - Collector Emitter Off-state Current



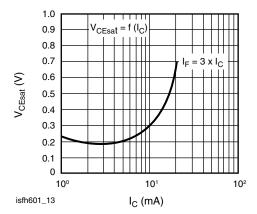


Fig. 13 - Saturation Voltage vs. Collector Current and Modulation Depth SFH601-1

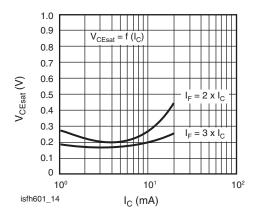


Fig. 14 - Saturation Voltage vs. Collector Current and Modulation Depth SFH601-2

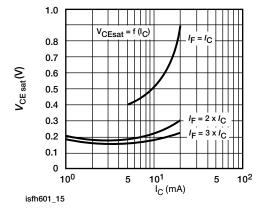


Fig. 15 - Saturation Voltage vs. Collector Current and Modulation Depth SFH601-3



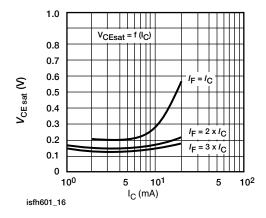


Fig. 16 - Saturation Voltage vs. Collector Current and Modulation Depth SFH601-4

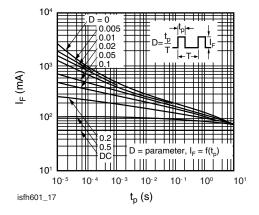


Fig. 17 - Permissible Pulse Load

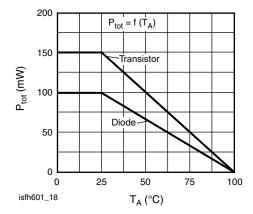


Fig. 18 - Permissible Power Dissipation for Transistor and Diode



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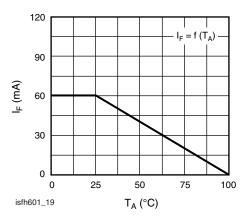
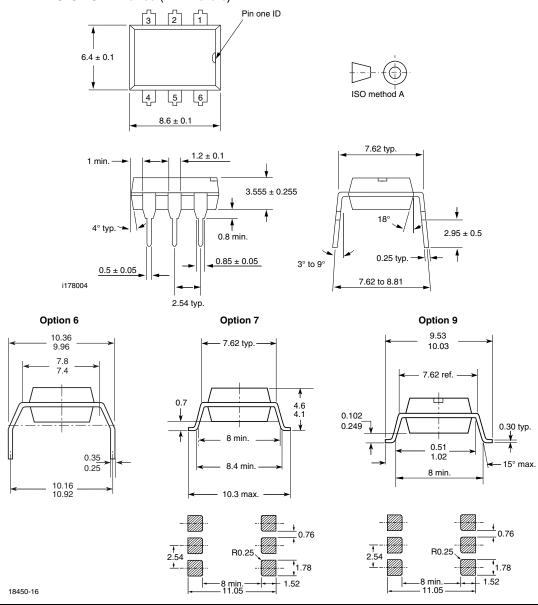


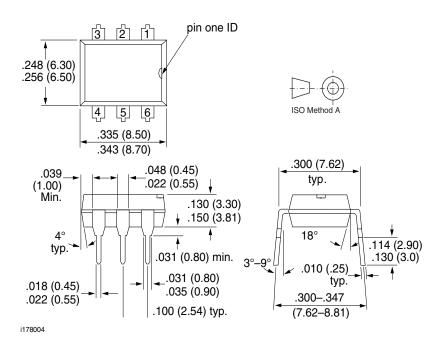
Fig. 19 - Permissible Forward Current Diode

#### **PACKAGE DIMENSIONS** in inches (millimeters)





# **Package Dimensions in Inches (mm)**



#### **Vishay Semiconductors**



#### Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operatingsystems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

#### We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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Vishay

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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

Revision: 02-Oct-12 Document Number: 91000

# AMEYA360 Components Supply Platform

# **Authorized Distribution Brand:**

























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